Lumped element kinetic inductance detectors (LEKIDs) have been widely developed for astronomical observations in the last decade. Their intrinsic frequency multiplexing property makes LEKIDs suitable for large detector arrays. In practice, the multiplexing factor per readout line depends on the readout bandwidth, resonance frequency spacing, and resonance width, which is usually limited by background radiation for ground-based observations. As the number of pixels per feedline increases, resonance frequency collision between adjacent resonators becomes problematic. When a collision happens, the readout tone may pick up signal from a nearby resonance. This affects the number of pixels that are useful for astronomical observations.

Frequency collision is usually caused by the variation of material parameters, such as the film thickness, the superconducting transition temperature, and the resonator dimensions across the wafer. Aluminium is commonly used in LEKIDs design for its easy fabrication, low gap frequency and long quasiparticle lifetime. Its low kinetic inductance and resistivity, however, impose thin films (< 80 nm) and narrow linewidths (< 4 μm), in order to optimize sensitivity and optical coupling. For example, the NIKA2 260 GHz array uses a 18 nm thick Al film with a 4 μm inductor width. Intrinsic variation in these parameters gives rise to a large, uncontrolled deviation of the resonance frequency from the design values, leading to many frequency collisions. This causes the number of functional pixels of the NIKA2 260 GHz array to decrease from 84% to 70% under sky background illumination.

Recently, a corrective technique has been developed, in which scatter in the resonance frequencies is mitigated by a second lithography step adapting the resonator capacitor. This technique has been deployed on LEKID arrays consisting of ~ 100 resonators. It has been shown that the deviation from design resonance frequency can be improved by a factor 10, going down from the few percent level to < 1%. Array yield has been shown to go up to 97% on a 1-inch 112-pixel array.

In this letter, we take this technique one step further, to a telescope-class, 4-inch kilo-pixel LEKID array. This array is designed for the 260 GHz band of the NIKA2 instrument with 2392 pixels, designed to have their resonance frequencies spaced by only 1.6 MHz. We have analysed the causes for resonance frequency deviation for 920 pixels from this array, and have applied our corrective technique to these pixels. We show that ~ 90% of the initial frequency deviation can be explained by geometric variations of the individual pixels, and that the technique is ready to be deployed on actual telescope-class arrays.

The detector array design in this study is based on the current NIKA2 260 GHz array. To optimally take advantage of the angular resolution possible at the IRAM 30-m telescope, the meandering inductor is reduced to a surface area of 1 × 1 mm. To fully cover the 80 mm diameter focal plane, the total number of pixels is increased to 2392, distributed over 8 feedlines. The resonators are made of t = 18 nm thick Al on a 250 μm-thick high-resistivity silicon substrate. In our design and calculations, we assumed a surface resistance $R_s = 1.6 \, \Omega/\square$ and a surface inductance $L_s = 2 \, \mu \text{H}/\square$. A 200 nm thick Al film is deposited on the back side of the wafer, serving as the ground of the microstrip feedline and the back-short for optical coupling. The inductor is shaped in a 3rd-order Hilbert curve with a width of 2.5 μm. An
8-finger interdigitated capacitor (IDC) is used to tune the resonance frequencies from 1.85 GHz to 2.35 GHz, by decreasing the IDC finger lengths pair by pair. On different feedlines, the number of resonators varies from 276 to 332 and the designed frequency spacing ranges from 1.51 MHz to 1.82 MHz. The electrical crosstalk, caused by the adjacent pixels in electromagnetic simulation, is optimized to be <55 kHz. The maximum crosstalk between feedlines is smaller than —21 dB. \( Q_c \) is optimized to 1 x 10^4 to match the expected internal quality factor under a 50 K sky radiation. The array design detail is shown in the supplementary material.

After fabrication, dicing and wire bonding, the array is cooled down to 100 mK in a dilution cryostat. Due to a limited number of connections in our test cryostat, only 4 out of 8 feedlines were connected. One feedline was found to be broken, the resulting measurements were performed on 3 feedlines with 920 designed resonators. Both S21 and mapping measurement were performed with the cryostat window open, so the performance of resonators was background radiation limited. To locate the position of the resonances on wafer, we performed an optical mapping on this array using a beam mapper. This mapper consists of a blackbody cooled down to 50 K, in front of which a moving 300 K metal ball acts as a source. The Teflon window of this mapper has a 20% emissivity.

The fractional frequency deviation calculated from Eqn. 1 with an offset of 35 x 10^-3 added. The fractional frequency deviation measured before trimming.

In order to understand the cause of this frequency deviation, we look at geometric variation. The resonance frequency is given by \( f = 1/(2\pi\sqrt{L_m + L_k/C}) \), with \( L_m \) the magnetic inductance, \( L_k \) the kinetic inductance, and \( C \) the capacitance. The magnetic inductance is determined by the inductor width \( L_m \propto 1/\sqrt{w} \). The kinetic inductance is given by \( L_k = L_n(l/w) \), where \( l \) is the inductor length. The variation of the surface inductance is mainly determined by variation of the thickness \( t \), with \( \delta L_n/L_n = -2\delta t/t \) in the thin-film limit. The capacitance variation, caused by the IDC finger width variation, is estimated from an electromagnetic simulation using Sonnet software, yielding \( \delta C/C = 0.383\delta w_c/w_c \), where \( w_c \) is the capacitor finger width. Using these dependencies, we estimate the frequency deviation by

\[
\frac{\delta f}{f} = \frac{1}{2} \left( \frac{\delta L_m + \delta L_k + \delta C}{L + C} \right)
\]

\[
= -\frac{1}{2} \left( -1 + \frac{\alpha \delta w}{w} - 2\alpha \frac{\delta t}{t} + 0.383 \frac{\delta w_c}{w_c} \right),
\]

with the kinetic inductance ratio \( \alpha = 46\% \).

Figure 1a-c show measurements of the relevant geometrical parameters of this array. The aluminium film thickness was measured before array fabrication, using ellipsometry. The thickness varies from 16.8 nm to 18.4 nm over the wafer, in a concentric fashion that is expected from thin film deposition using e-beam evaporation. The inductor width \( w \) and IDC finger width \( w_c \) are measured for each individual pixel using scanning electron microscopy (SEM). Both dimensions show a large variation, with notably a large size reduction in the center of the array. These variations are possibly due to variations in the photolithography process, or variations in local wet etching speed, and are currently under investigation.

Taking the measured variations in pixel dimensions, the expected frequency deviation is shown in Fig. 1e.
FIG. 2: (a) The difference of $\delta f/f$ between calculation and measurement (Fig. 1d and e). (b) Histograms of the difference. The standard deviation of the residuals is $8 \times 10^{-3}$.

In the optical mapping, the positions of 635 (69%) resonators were identified. For the unidentified resonators, we used radial basis functions to interpolate or extrapolate their resonance frequencies. We re-designed the resonance frequencies after trimming as $f_{\text{redes}}$, ranging from 1.955 GHz to 2.455 GHz for each feedline. As both $f_{\text{des}}$ and $f_{\text{redes}}$ use the same relation between IDC finger lengths and resonance frequencies, the corresponding trimming frequencies of the patterns on the trimming mask are given by $f_{\text{trim}} = f_{\text{des}} f_{\text{redes}}/f_{\text{meas}}$, assuming the same frequency deviation

$$\frac{\delta f}{f} = \frac{f_{\text{redes}} - f_{\text{trim}}}{f_{\text{trim}}}. \tag{2}$$

The final trimming mask is defined by the difference of the IDC patterns between $f_{\text{des}}$ and $f_{\text{trim}}$ designs.

As described before, the trimming process consists of a contact lithography and Al wet-etching step. As the photosist residue in small patterns can block wet-etching, an oxygen plasma was applied to remove the residue after development. During etching process, a large part of the backside 200 nm Al was etched away, so a new layer of 200 nm Al was sputtered on top of the Al residue.

After trimming, the array is re-bonded and cooled down to 100 mK using the same setup as in the first characterization. S21 and mapping measurements are applied on the same three feedlines. The resonance frequencies after trimming $f_{\text{remeas}}$ range as the redesigned frequency $f_{\text{redes}}$. The frequency deviation ranges from $-4 \times 10^{-3}$ to $2 \times 10^{-3}$, and is decreased by a factor of 10. From Fig. 3a, the mapping shows two groups of resonators on the array. One group has $\delta f/f < 0$, as expected, and its mean deviation of -1.7 MHz is consistent with previous trimming results. This common change in resonance frequency is also observed on other aluminium arrays and is probably due to Al film aging. The second group has $\delta f/f > 0$. The group is located at the upper region of the array, and partly overlaps with the region where the residuals are larger, as shown in Fig. 2. As discussed before, the Al film in this region may have different superconducting properties caused by argon cleaning before deposition or the Al evaporation process. Our trimming accuracy shows that the use of a radial basis function to
inter/extrapolate the resonance frequencies is acceptable on large format arrays. We also notice that trimming one or two pairs of IDC fingers give similar accuracy. 

$Q_r$ and $Q_i$ are extracted from $S_{21}$ measured using VNA under a 110 K background of the mapping system. After trimming, the $Q_r \sim 10^4$ remains the same, while the $Q_i$, limited by background radiation, decreases by 40 $\%$, from $14 \times 10^3$ to $8.4 \times 10^3$. The resonances shown in the histogram as $Q_i = 0$ do not have proper fitting results due to frequency collision. After trimming, the inductor geometry is unchanged and the background temperature of the mapping system is stable, so the decrease of the background-limited $Q_i$ indicates an increase of quasiparticle density. The high trimming accuracy of $\delta f/f < 2 \times 10^{-3}$ suggests that the change of resistivity and gap energy of the Al film should also be at the same level, according to $L_s = hR_s/\pi \Delta$, which cannot explain this 40 $\%$ degradation of $Q_i$. Using Mattis-Bardeen theory \cite{19}, the equivalent temperatures of the optical loaded $Q_i$ are 334 mK and 361 mK before and after trimming. The heat sinking of the array is determined by the contact between the back short Al film and the aluminium sample holder. The small difference in equivalent temperature suggests that a small change in the heat sinking could explain the measurements. In future, heat sinking can be improved using a backshort made of a Ti-Au bilayer, which will both trap phonons \cite{10} and improve heat-sinking. The peak response of the mapping source decreases from 4.6 kHz to 3.9 kHz after trimming (Fig. 4), consistent with the 21 $\%$ decrease of $Q_r$ from $9.3 \times 10^3$ to $7.3 \times 10^3$.

Here we discuss the yield of this array under the 110 K blackbody radiation, a typical on-telescope condition. For reference, the on-telescope sky background radiation varies from 30 K to 180 K depending on the atmospheric opacity \cite{7}. After trimming, the yield is increased from 69 $\%$ to 76 $\%$ counted from optical mapping results. For all counted pixels, no crosstalk is observed from the 2-dimensional mapping results, with signal to noise ratio of 10. 45 resonators are missed by the readout system due to the limited number of readout tones. Including these missed resonators, the final yield is 81 $\%$, 10 $\%$ higher than the on-telescope yield of the current NIKA2 260 GHz array\cite{9}, while the initial fabrication yield is 84 $\%$ for both arrays. The yield could be further increased by improving our fabrication process. 23 resonances were broken during trimming process, giving the trimming fabrication yield of 97 $\%$.

In conclusion, we have studied and minimized the resonance frequency deviations in a 4-inch kilo-pixel LEKID array. The calculation agrees with the measurement within an accuracy of $\sim 20 \times 10^{-3}$. The decrease of the optical-loaded quality factor, after trimming, could be explained by a degradation of the heat sinking instead of a film property change. After trimming, the mapping yield, measured under a 110 K background, is improved from 69 $\%$ to 76 $\%$, which can be further improved to 81 $\%$ after updating our readout system. This 7 $\%$ improvement in yield within fixed readout bandwidth suggests that the trimming technique is capable to improve the on-telescope yield, which will benefit future large-format LEKID arrays.

See supplementary material for the design in detail. The data that support the findings of this study are available from the corresponding author upon reasonable request.

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I. SUPPLEMENTARY MATERIAL

A. Array design

The whole focal plane of the NIKA2 instrument is a 80 mm diameter circle. With inductor size of 1 mm, in total there are 2392 resonators on 8 microstrip feedlines. The pitch size is optimized to be 1.4 mm. The single pixel design is shown in Fig. 5 in detail. Resonance frequencies are tune by shortening the length of IDC fingers pair by pair. The longest finger length is 960 µm and the shortest length is 500 µm. The resonance frequencies are simulated in Sonnet software with several different IDC finger lengths. A polynomial fit is applied to extracted the relation between finger length and resonance frequencies, shown in Fig. 6. The fitting residue is smaller than ±0.1 µm. In terms of resonance frequency, this 0.1 µm corresponds to 5 kHz, much smaller than the simulated < 55 kHz electrical crosstalk. The resonance frequency after trimming is also defined in this way, so no extra simulations are needed for the re-designed resonance frequencies. The full array after fabrication is shown in Fig. 7.

FIG. 5: A single LEKID pixel design in detail.
FIG. 6: Design of the resonance frequency by changing the length of capacitor fingers. The simulated data is fitted using polynomial functions. The residue is within 100 nm.

FIG. 7: The photo of this 4-inch array in a detector holder.